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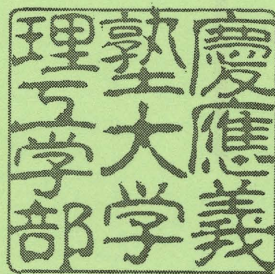
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EFFECT OF SUBBAND-INTERACTION ON
RELAXATION TIME OF HOLE IN *p*-TYPE
SILICON AND GERMANIUM

By

K. TAKEDA, K. SAKUI, A. TAGUCHI AND
M. SAKATA



FACULTY OF SCIENCE AND TECHNOLOGY
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